NSN 5961-01-434-0312

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View Online at https://aerobasegroup.com/nsn/5961-01-434-0312 **Inclosure Material:** Ceramic **Overall Length:** 0.414 inches **Overall Height:** 0.071 inches **Overall Width:** 0.414 inches **End Application:** Pacer dawn **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 25.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 70.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 290.0 milliwatts small-signal input power, common-emitter nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees fahrenheit junction **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: